Dual Schmitt-Trigger Inverter

The NLX2G14 MiniGate[™] is an advanced high-speed CMOS dual Schmitt-trigger inverter in ultra-small footprint.

The NLX2G14 input and output structures provide protection when voltages up to 7.0 V are applied, regardless of the supply voltage.

The NLX2G14 can be used to enhance noise immunity or to square up slowly changing waveforms.

Features

- Designed for 1.65 V to 5.5 V V_{CC} Operation
- Low Power Dissipation: $I_{CC} = 1 \mu A \text{ (Max)}$ at $T_A = 25^{\circ}\text{C}$
- 24 Balanced Output Source and Sink Capability
- Balanced Propagation Delays
- Overvoltage Tolerant (OVT) Input and Output Pins
- Ultra-Small Packages
- These are Pb–Free Devices

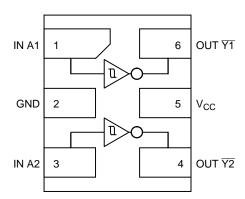


Figure 1. Pinout (Top View)

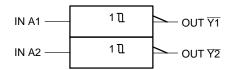


Figure 2. Logic Symbol

FUNCTION TABLE

| Α | Y |
|--------|----|
| L H | ΗL |

| 1 | IN A1 |
|---|-----------------|
| 2 | GND |
| 3 | IN A2 |
| 4 | OUT Y2 |
| 5 | V _{CC} |
| 6 | OUT Y1 |

PIN ASSIGNMENT



ON Semiconductor®

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MARKING DIAGRAMS



UDFN6 1.0 x 1.0 CASE 517BX





UDFN6 1.2 x 1.0 CASE 517AA





UDFN6 1.45 x 1.0 CASE 517AQ



T = Device Marking*
M = Date Code
* Rotated 90° clockwise

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

MAXIMUM RATINGS

| Symbol | Paramete | Value | Unit | |
|----------------------|---|------------------------|----------------------|----|
| V _{CC} | DC Supply Voltage | | -0.5 to +7.0 | V |
| V _{IN} | DC Input Voltage | -0.5 to +7.0 | V | |
| V _{OUT} | DC Output Voltage | | -0.5 to +7.0 | V |
| I _{IK} | DC Input Diode Current | V _{IN} < GND | -50 | mA |
| l _{ok} | DC Output Diode Current | V _{OUT} < GND | -50 | mA |
| I _O | DC Output Source/Sink Current | ±50 | mA | |
| I _{CC} | DC Supply Current Per Supply Pin | ±100 | mA | |
| I _{GND} | DC Ground Current per Ground Pin | ±100 | mA | |
| T _{STG} | Storage Temperature Range | -65 to +150 | °C | |
| TL | Lead Temperature, 1 mm from Case for 10 Se | conds | 260 | °C |
| TJ | Junction Temperature Under Bias | 150 | °C | |
| MSL | Moisture Sensitivity | | Level 1 | |
| F _R | Flammability Rating Oxygen | Index: 28 to 34 | UL 94 V-0 @ 0.125 in | |
| I _{LATCHUP} | Latchup Performance Above V _{CC} and Below 0 | ±500 | mA | |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow.
- Tested to EIA/JESD22-A114-A.
 Tested to EIA/UESD22-A115-A.
- 4. Tested to JESD22-C101-A.
- 5. Tested to EIA / JESD78.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Para | Min | Max | Unit | |
|------------------|------------------------------------|--|--------|----------------------|------|
| V _{CC} | Positive DC Supply Voltage | 1.65 | 5.5 | V | |
| V _{IN} | Digital Input Voltage | 0 | 5.5 | V | |
| V _{OUT} | Output Voltage | 0 | 5.5 | V | |
| T _A | Operating Free–Air Temperature | | -55 | +125 | °C |
| Δt/ΔV | Input Transition Rise or Fall Rate | $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ $V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$ | 0 0 | No Limit No Limit | ns/V |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

| | | | V _{CC} | T _A = 25°C | | T _A = - | +85°C | T _A = -5 +12 | 55°C to 5°C | | |
|------------------|---|--|---|---|---|---|---|---|---|---|----------|
| Symbol | Parameter | Conditions | (V) | Min | Тур | Max | Min | Max | Min | Max | Unit |
| V _{T+} | Positive Threshold Voltage | | 1.65 2.3 2.7 3.0 4.5 5.5 | 0.6 1.0 1.2 1.3 1.9 2.2 | 1.0 1.5 1.7 1.9 2.7 3.3 | 1.4 1.8 2.0 2.2 3.1 3.6 | 0.6 1.0 1.2 1.3 1.9 2.2 | 1.4 1.8 2.0 2.2 3.1 3.6 | 0.6 1.0 1.2 1.3 1.9 2.2 | 1.4 1.8 2.0 2.2 3.1 3.6 | V |
| V _T _ | Negative Threshold Voltage | | 1.65 2.3 2.7 3.0 4.5 5.5 | 0.2 0.4 0.5 0.6 1.0 | 0.5 0.75 0.87 1.0 1.5 | 0.8 1.15 1.4 1.5 2.0 2.3 | 0.2 0.4 0.5 0.6 1.0 | 0.8 1.15 1.4 1.5 2.0 2.3 | 0.2 0.4 0.5 0.6 1.0 | 0.8 1.15 1.4 1.5 2.0 2.3 | > |
| V _H | Hysteresis Voltage | | 1.65 2.3 2.7 3.0 4.5 5.5 | 0.1 0.25 0.3 0.4 0.6 0.7 | 0.48 0.75 0.83 0.93 1.2 1.4 | 0.9 1.1 1.15 1.2 1.5 1.7 | 0.1 0.25 0.3 0.4 0.6 0.7 | 0.9 1.1 1.15 1.2 1.5 1.7 | 0.1 0.25 0.3 0.4 0.6 0.7 | 0.9 1.1 1.15 1.2 1.5 1.7 | V |
| V _{OH} | Minimum High-Level | $V_{IN} \le V_{T-MIN}$ $I_{OH} = -100 \mu\text{A}$ | 1.65– 5.5 | V _{CC} - 0.1 | V _{CC} | | V _{CC} - 0.1 | | V _{CC} - 0.1 | | V |
| | Output Voltage | $\begin{array}{c} V_{IN} \leq V_{T-MIN} \\ I_{OH} = -4 \text{ mA} \\ I_{OH} = -8 \text{ mA} \\ I_{OH} = -12 \text{ mA} \\ I_{OH} = -16 \text{ mA} \\ I_{OH} = -24 \text{ mA} \\ I_{OH} = -32 \text{ mA} \end{array}$ | 1.65 2.3 2.7 3.0 3.0 4.5 | 1.29 1.9 2.2 2.4 2.3 3.8 | 1.52 2.1 2.4 2.7 2.5 4.0 | | 1.29 1.9 2.2 2.4 2.3 3.8 | | 1.29 1.8 2.1 2.3 2.2 3.7 | | |
| V _{OL} | Maximum Low-Level Output | $V_{IN} \ge V_{T+MAX}$ $I_{OL} = 100 \mu A$ | 1.65– 5.5 | | 0 | 0.1 | | 0.1 | | 0.1 | V |
| | Voltage | $\begin{array}{l} V_{\text{IN}} \geq V_{\text{T+MAX}} \\ I_{\text{OH}} = -4 \text{ mA} \\ I_{\text{OH}} = -8 \text{ mA} \\ I_{\text{OH}} = -12 \text{ mA} \\ I_{\text{OH}} = -16 \text{ mA} \\ I_{\text{OH}} = -24 \text{ mA} \\ I_{\text{OH}} = -32 \text{ mA} \end{array}$ | 1.65 2.3 2.7 3.0 3.0 4.5 | | 0.08 0.2 0.22 0.28 0.38 0.42 | 0.24 0.3 0.4 0.4 0.55 0.55 | | 0.24 0.3 0.4 0.4 0.55 0.55 | | 0.24 0.4 0.5 0.5 0.55 0.65 | |
| I _{IN} | Input Leakage Current | $0 \le V_{IN} \le 5.5 V$ | 0 to 5.5 | | | ±0.1 | | ±1.0 | | ±1.0 | μΑ |
| I _{OFF} | Power-Off Output Leakage Current | V _{OUT} = 5.5 V | 0 | | | 1.0 | | 10 | | 10 | μΑ |
| I _{CC} | Quiescent Supply Current | $0 \le V_{IN} \le V_{CC}$ | 5.5 | | | 1.0 | | 10 | | 10 | μΑ |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ ns}$)

| | | V _{CC} | Test | 7 | T _A = 25°C | ; | T _A = - | +85°C | T _A = - to +1 | | |
|--|---|-----------------|---|-----|-----------------------|-----|--------------------|-------|-----------------------------|-----|------|
| Symbol | Parameter | (V) | Condition | Min | Тур | Max | Min | Max | Min | Max | Unit |
| t _{PLH} , t _{PHL} | Propagation Delay, Input A to Output Y | 2.3–2.7 | $R_L = 1 M\Omega$, $C_L = 15 pF$ | 1.8 | 4.3 | 7.4 | 1.8 | 8.1 | 1.8 | 9.1 | ns |
| | | 3.0-3.6 | $R_L = 1 M\Omega$, $C_L = 15 pF$ | 1.5 | 3.3 | 5.0 | 1.5 | 5.5 | 1.5 | 6.5 | |
| | | | $R_L = 500 \Omega,$ $C_L = 50 pF$ | 1.8 | 4.0 | 6.0 | 1.8 | 6.6 | 1.8 | 7.6 | |
| | | 4.5–5.5 | $R_L = 1 M\Omega$, $C_L = 15 pF$ | 1.0 | 2.7 | 4.1 | 1.0 | 4.5 | 1.0 | 5.5 | |
| | | | $R_L = 500 \Omega,$ $C_L = 50 pF$ | 1.2 | 3.2 | 4.9 | 1.2 | 5.4 | 1.2 | 6.4 | |
| C _{IN} | Input Capacitance | 5.5 | V _{IN} = 0 V or V _{CC} | | 2.5 | | | | | | pF |
| C _{PD} | Power Dissipation Capacitance (Note 6) | 3.3 5.5 | 10 MHz V _{IN} = 0 V or V _{CC} | | 11 12.5 | | | | | | pF |

^{6.} C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation I_{CC(OPR)} = C_{PD} • V_{CC} • f_{in} + I_{CC}. C_{PD} is used to determine the no–load dynamic power consumption: P_D = C_{PD} • V_{CC}² • f_{in} + I_{CC} • V_{CC}.

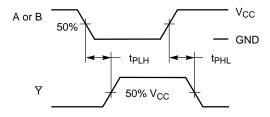
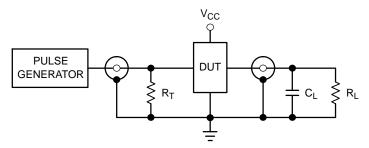


Figure 3. Switching Waveforms



 $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)

Figure 4. Test Circuit

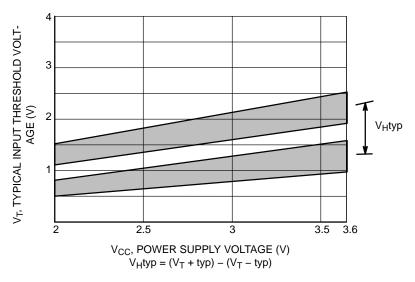
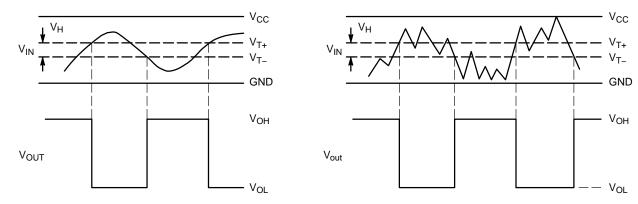


Figure 5. Typical Input Threshold, V_T+, V_T-versus Power Supply Voltage



(a) A Schmitt-Trigger Squares Up Inputs With Slow Rise and Fall Times

(b) A Schmitt-Trigger Offers Maximum Noise Immunity

Figure 6. Typical Schmitt-Trigger Applications

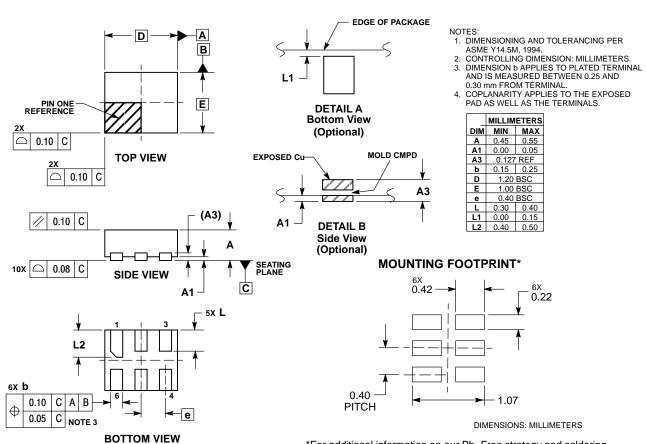
ORDERING INFORMATION

| Device | Package | Shipping [†] |
|---------------|--------------------------------------|-----------------------|
| NLX2G14MUTCG | UDFN6, 1.2 x 1.0, 0.4P (Pb-Free) | 3000 / Tape & Reel |
| NLX2G14AMUTCG | UDFN6, 1.45 x 1.0, 0.5P (Pb-Free) | 3000 / Tape & Reel |
| NLX2G14CMUTCG | UDFN6, 1.0 x 1.0, 0.35P (Pb-Free) | 3000 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

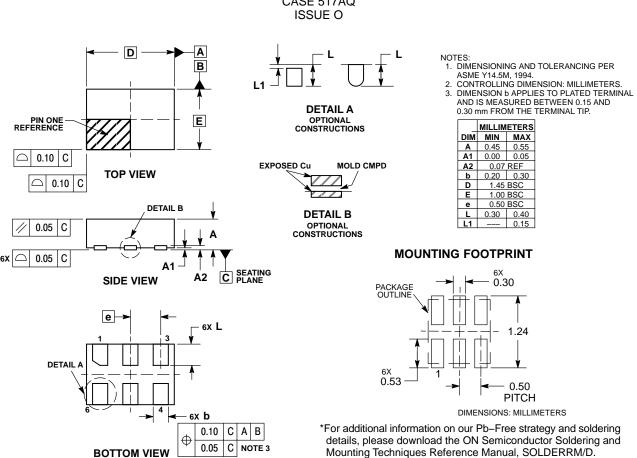
PACKAGE DIMENSIONS

UDFN6, 1.2x1.0, 0.4P CASE 517AA ISSUE D



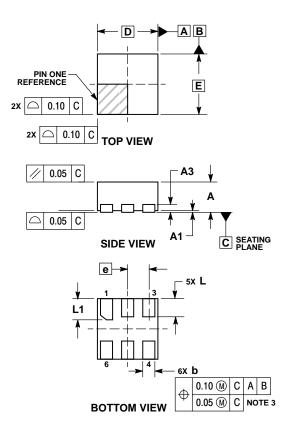
PACKAGE DIMENSIONS

UDFN6 1.45x1.0, 0.5P CASE 517AQ



PACKAGE DIMENSIONS

UDFN6 1.0x1.0. 0.35P CASE 517BX **ISSUE O**

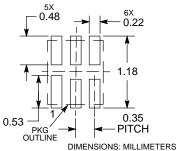


NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP. PACKAGE DIMENSIONS EXCLUSIVE OF
- BURRS AND MOLD FLASH.

| | MILLIMETERS | | | | | |
|-----|-------------|------|--|--|--|--|
| DIM | MIN | MAX | | | | |
| Α | 0.45 | 0.55 | | | | |
| A1 | 0.00 | 0.05 | | | | |
| A3 | 0.13 REF | | | | | |
| b | 0.12 | 0.22 | | | | |
| D | 1.00 BSC | | | | | |
| E | 1.00 BSC | | | | | |
| е | 0.35 BSC | | | | | |
| L | 0.25 | 0.35 | | | | |
| L1 | 0.30 | 0.40 | | | | |

RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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